

Igor Trunkin

List of Publications by Year in descending order

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22
papers

96
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1683354

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docs citations

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131
citing authors

#	ARTICLE	IF	CITATIONS
1	Biopolymer-based hydrogels for encapsulation of photocatalytic TiO ₂ nanoparticles prepared by the freezing/thawing method. <i>Journal of Molecular Liquids</i> , 2016, 223, 16-20.	2.3	25
2	Effect of (100) GaAs substrate misorientation on electrophysical parameters, structural properties and surface morphology of metamorphic HEMT nanoheterostructures InGaAs/InAlAs. <i>Journal of Crystal Growth</i> , 2014, 392, 11-19.	0.7	12
3	Nanoarchitecture: Toward Quantum Size Tuning of Superconductivity. <i>Physica Status Solidi - Rapid Research Letters</i> , 2019, 13, 1800317.	1.2	9
4	New Structure for Photoconductive Antennas Based on {LTG-GaAs/GaAs:Si} Superlattice on GaAs(111)A Substrate. <i>Crystallography Reports</i> , 2019, 64, 205-211.	0.1	7
5	Grazing-incidence small-angle X-ray scattering study of correlated lateral density fluctuations in W/Si multilayers. <i>Acta Crystallographica Section A: Foundations and Advances</i> , 2019, 75, 342-351.	0.0	7
6	Influence of arsenic flow on the crystal structure of epitaxial GaAs grown at low temperatures on GaAs (100) and (111)A substrates. <i>Crystallography Reports</i> , 2017, 62, 82-90.	0.1	5
7	High-Quality AlN Layers Grown on Si(111) Substrates by Metalorganic Chemical Vapor Deposition. <i>Crystallography Reports</i> , 2020, 65, 122-125.	0.1	5
8	Electrophysical and structural properties of the composite quantum wells In _{0.52} Al _{0.48} As/In _x Ga _{1-x} As/In _{0.52} Al _{0.48} As with ultrathin InAs inserts. <i>Journal of Materials Research</i> , 2015, 30, 3020-3025.	0.1	5
9	Method of Preparation of Composite Materials Filled with Copper and Copper Sulfide Nanoparticles. <i>Russian Journal of Physical Chemistry B</i> , 2020, 14, 323-331.	0.2	4
10	Structural and electrical properties of InAlAs/InGaAs/InAlAs HEMT heterostructures on InP substrates with InAs inserts in quantum well. <i>Crystallography Reports</i> , 2014, 59, 900-907.	0.1	3
11	The microstructure of Nb ₃ Sn superconductors differing in the number of copper inserts at various stages of heat treatment. <i>IOP Conference Series: Materials Science and Engineering</i> , 0, 502, 012174.	0.3	3
12	Microstructure of QD-like clusters in GaAs/In(As,Bi) heterosystems. <i>Journal of Materials Research</i> , 2018, 33, 2342-2349.	1.2	2
13	Structural Study of Defects in Granulated EP741NP Nickel Alloy. <i>Crystallography Reports</i> , 2019, 64, 570-574.	0.1	2
14	Structural Characteristics of Epitaxial Low-Temperature Grown {InGaAs/InAlAs} Superlattices on InP(100) and InP(111)A Substrates. <i>Crystallography Reports</i> , 2020, 65, 496-501.	0.1	2
15	Structural and electrophysical properties of In _{0.52} Al _{0.48} As/In _{0.53} Ga _{0.47} As/In _{0.52} Al _{0.48} As/InP HEMT nanoheterostructures with different combinations of InAs and GaAs inserts in quantum well. <i>Crystallography Reports</i> , 2015, 60, 397-405.	0.1	1
16	High-resolution X-ray diffractometry and transmission electron microscopy as applied to the structural study of InAlAs/InGaAs/InAlAs multilayer transistor nanoheterostructures. <i>Journal of Surface Investigation</i> , 2016, 10, 495-509.	0.1	1
17	Crystal structure of stacking faults in InGaAs/InAlAs/InAs heterostructures. <i>Crystallography Reports</i> , 2017, 62, 265-269.	0.1	1
18	Epitaxial low-temperature growth of In _{0.5} Ga _{0.5} As films on GaAs(100) and GaAs(111)A substrates using a metamorphic buffer. <i>Crystallography Reports</i> , 2017, 62, 947-954.	0.1	1

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19	Low-Temperature epitaxial growth of InGaAs films on InP(100) and InP(411)A substrates. Crystallography Reports, 2017, 62, 589-596.	0.1	0
20	Synthesis and functional characterization of poly(p-xylylene)-MnSb nanocomposite films. Journal of Physics: Conference Series, 2019, 1389, 012042.	0.3	0
21	Manufacturing particularities of hollow metal medieval buttons (from the excavations on the) Tj ETQq1 1 0.784314 rgBT /Overlock 10		
22	Study of a reliquary cross from the Novodevichy Convent with natural science techniques. Rossijskaja Arheologija, 2020, , 165-183.	0.2	0